# SMIC28: 3.3V Support: Power



#### Libraries

Name	Process	Form Factor
RGO_SMIC28_18V33_HKCP_20C_SPT	HKC+	Staggered CUP
RGO_SMIC28_18V33_HKCP_40C_SPT	HKC+	Inline CUP

## Summary

The 3.3V Support: Power library provides a full complement of cells to support the assembly of a complete pad ring by abutment. It is supplied as a standard addition to the GPIO libraries and other I/O library offerings from Aragio Solutions that use a compatible pad ring bus structure.

These 28nm libraries are available in inline and staggered CUP wire bond implementations with a flip chip option.

The included rail splitter allows multiple power domains to be isolated in the same pad ring while maintaining continuous VDD/VSS for robust ESD protection.

#### **ESD Protection:**

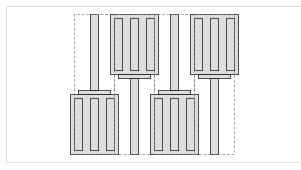
- JEDEC compliant
  - 2KV ESD Human Body Model (HBM)
  - o 500 V ESD Charge Device Model (CDM)

#### Latch-up Immunity:

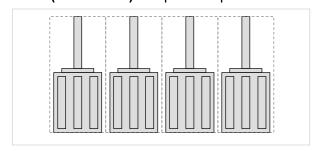
- JEDEC compliant
  - Tested to I-Test criteria of  $\pm 100$ mA @ 125°C

### **Cell Size & Form Factor**

# Staggered (pad-limited) - 25 µm x 165 µm



## Inline (core-limited) – 45µm x 100µm



#### **Cell List**

Description			
Digital Pads			
Input-only buffer			
I/O power (DVDD)			
I/O ground (DVSS)			
Core power (VDD)			
Core ground (VSS)			
Analog Input cell			
s			
Analog power (AVDD) 1.0V			
Analog ground (AVSS)			
Analog power (ADVDD) 3.3V			
Analog ground (ADVSS)			
Corner cell (rail splitter)			
Corner cell (continuous)			
0.1µm spacer			
1µm spacer			
5µm spacer			
10µm spacer			
Rail splitter			
VREF generation			
POC / HVPS generation			

\* Vertical-only (\_V) and horizontal only(\_H) variants provided Cell names / descriptions abbreviated

Staggered CUP Cells	
CUP_SMIC28_44X80_IN	44μm X 80μm Inner
CUP_SMIC28_44X80_OUT	44μm X 80μm Outer
CUP_SMIC28_46P7X80_IN	46.7µm X 80µm Inner
CUP_SMIC28_46P7X80_OUT	46.7µm X 80µm Outer
CUP_SMIC28_48X48_IN	48µm X 48µm Inner
CUP_SMIC28_48X48_OUT	48µm X 48µm Outer
CUP_SMIC28_48X63_IN	48μm X 63μm Inner
CUP_SMIC28_48X63_OUT	48µm X 63µm Outer
CUP_SMIC28_33V_FC	Flip chip with top metal port
CUP_SMIC28_33V_FC_NRV	Flip chip without RV via

Inline CUP Cells		
CUP_SMIC28_40X80_INLINE	40μm X 80 μm Inline	
CUP_SMIC28_44X80_INLINE	44μm X 80 μm Inline	
CUP_SMIC28_48P9X80_INLINE	48.9μm X 80 μm Inline	
CUP_SMIC28_50X50_INLINE	50μm X 50 μm Inline	
CUP SMIC28 INLINE FC	Flip chip with top metal port	

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## **Recommended operating conditions**

	Description	Min	Nom	Max	Units
$V_{VDD}$	Core supply voltage	0.81	0.90	0.99	V
V <sub>DVDD</sub>	I/O supply voltage	2.97	3.3	3.63	V
		2.25	2.5	2.75	V
		1.62	1.8	1.98	V
TJ	Junction temperature	-40	25	125	°C
$V_{PAD}$	Voltage at PAD	V <sub>DVSS</sub> -0.3	-	V <sub>DVDD</sub> +0.3	V

## **Characterization Corners**

Model	LPE Type	VDD=0.9V	DVDD [1]	Temp
FFG	Cbest	+10%	+10%	-40°C
FFG	Cbest	+10%	+10%	0°C
FFG	Ctypical	+10%	+10%	125°C
TT	Ctypical	nominal	nominal	25°C
TT	Ctypical	nominal	nominal	85°C
SSG	Cworst	-10%	-10%	-40°C
SSG	Cworst	-10%	-10%	0
SSG	Cworst	-10%	-10%	125°C

[1] DVDD = 1.8V, 2.5V & 3.3V

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